

DIAC

Features

1. V_{BO} : 40V
2. Breakover voltage range: 35 to 45V



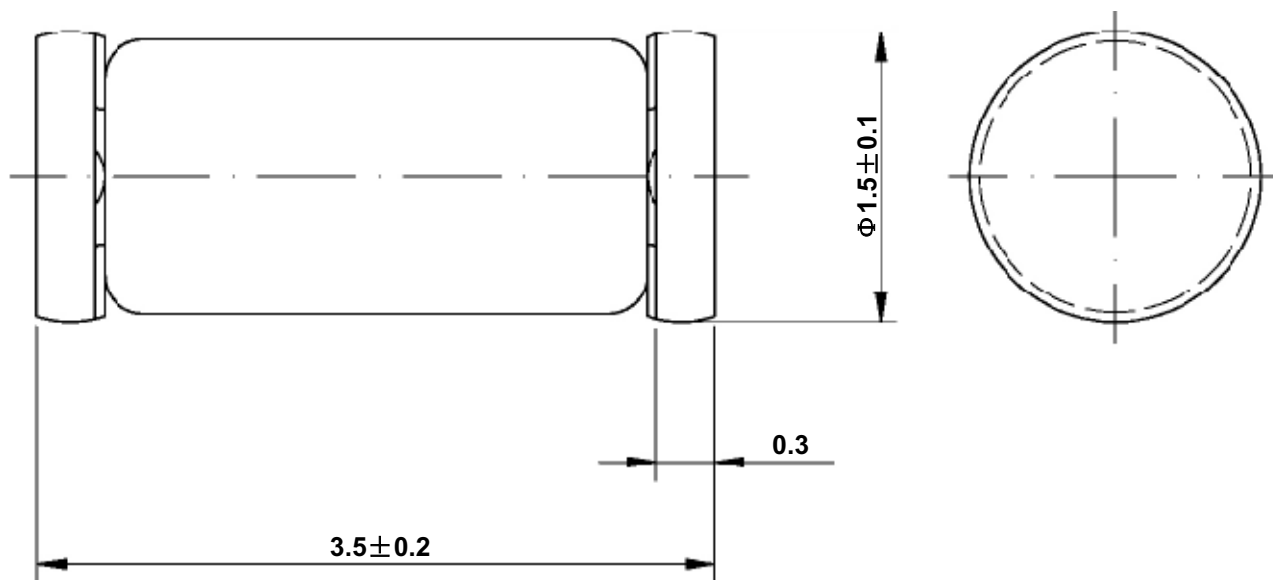
Applications

Functioning as a trigger diode with a fixed voltage reference, the LLDB4 can be used in conjunction with triacs for simplified gate control circuits or as a starting element in fluorescent lamp ballasts.

Absolute Maximum Ratings

(Limiting values)

Parameter	Symbol	Value	Unit
Repetitive peak on-state current ($t_p=20\ \mu\text{s}$ $F=120\text{ Hz}$)	I_{TRM}	2	A
Operating junction temperature range	T_j	-40 ~ +125	°C
Storage temperature range	T_{stg}	-40 ~ +125	°C

Dimensions in mm

Glass Case
Mini Melf / SOD 80
JEDEC DO 213 AA

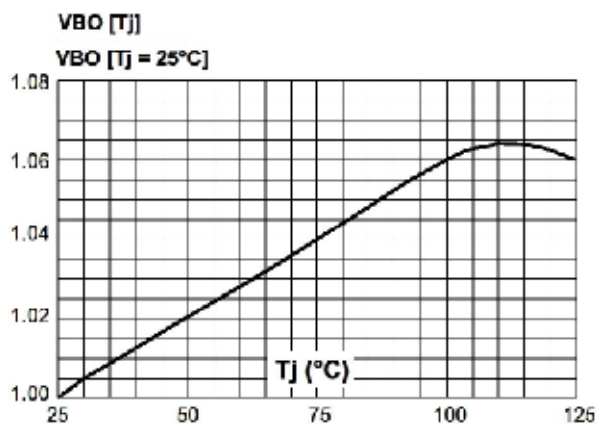


Figure 1. Relative variation of VBO versus junction temperature (typical values)

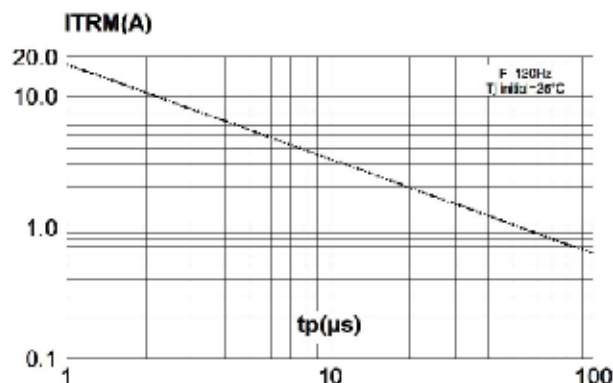


Figure 2. Repetitive peak pulse current versus pulse duration (maximum values)

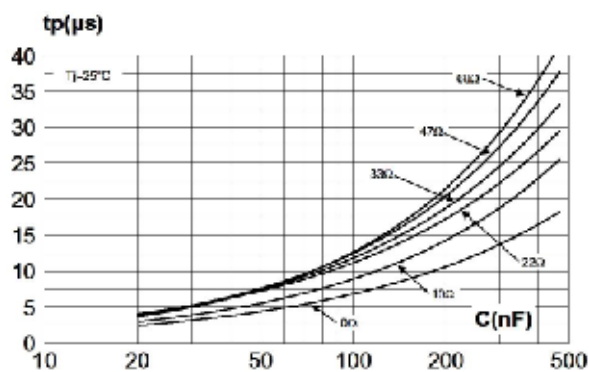


Figure 3. Time duration while current pulse is higher 50 mA versus C and Rs (typical values)

Electrical Characteristics

(T_j=25°C unless otherwise specified)

Parameter	Symbol	Test Conditions		Value	Unit
Breakover voltage*	V _{BO}	C=22nF**	MIN.	35	V
			TYP.	40	
			MAX.	45	
Breakover voltage symmetry	V _{BO1} -V _{BO2}	C=22nF**	MAX.	±3	V
Dynamic breakover voltage*	△V	V _{BO} and V _F at 10mA	MIN.	5	V
Output voltage*	V _O	see diagram 2(R=20 Ω)	MIN.	5	V
Breakover current*	I _{BO}	C=22nF**	MAX.	50	μ A
Rise time*	tr	see diagram 3	MAX.	2	μ s
Leakage current*	I _R	V _R =0.5V _{BO} max	MAX.	10	μ A

*Applicable to both forward and reverse directions.

**Connected in parallel to the device.

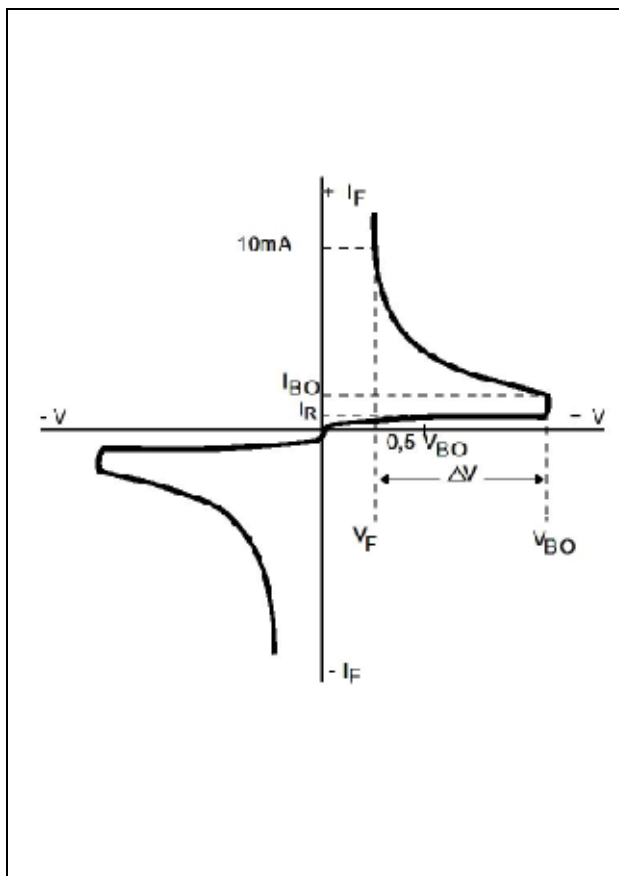


Diagram 1. Voltage – current characteristic curve

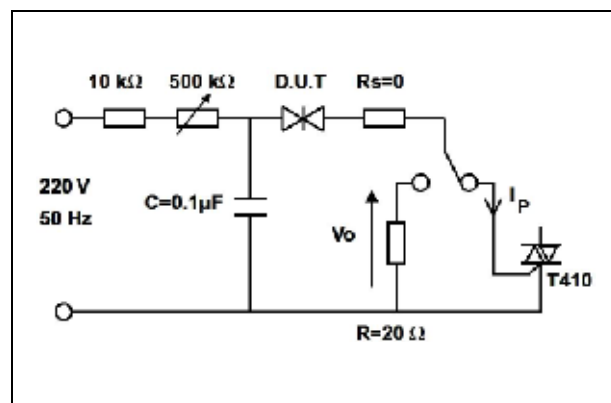


Diagram 2. Test circuit

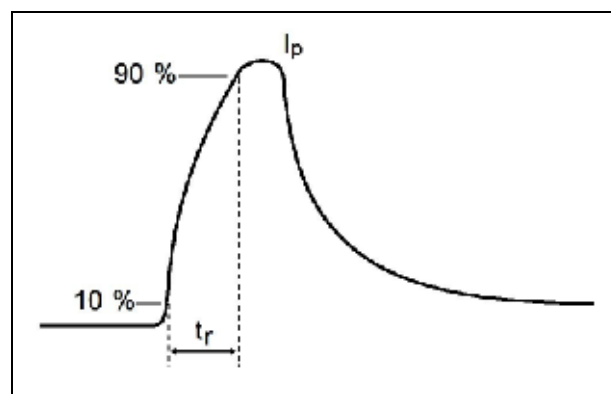


Diagram 3. Rise time measurement